# NSN 5961-01-326-2791

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## **Inclosure Material:**

Metal and glass

## **Overall Length:**

Between 1.439 inches and 1.573 inches

## **Overall Height:**

Between 0.270 inches and 0.380 inches

## **Overall Width:**

Between 0.990 inches and 1.050 inches

## Mounting Facility Quantity:

2

# Internal Configuration:

Junction contact

#### **Mounting Method:**

Unthreaded hole

#### Features Provided:

Burn in

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

650.0 collector to base voltage/static/emitter open and 400.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage,

static, collector open

## **Current Rating Per Characteristic:**

Between 4.00 amperes source cutoff current and 8.00 amperes source cutoff current

## Power Rating Per Characteristic:

6.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

## **Special Features:**

Junction pattern arrangement: npn

## **Terminal Type And Quantity:**

2 pin and 1 case

Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

No

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